	Data Sheet
	2N6053 2N6054 PNP 2N6055 2N6056 NPN
Semiconductor Corp.	COMPLEMENTARY SILICON DARLINGTON POWER TRANSISTOR
145 Adams Avenue, Hauppauge, NY 11788 USA Tel: (631) 435-1110 • Fax: (631) 435-1824	JEDEC TO-3 CASE
Manufacturers of World Class Discrete Semiconductors	

DESCRIPTION

The CENTRAL SEMICONDUCTOR 2N6053, 6055 Series types are Complementary Silicon Darlington Power Transistors designed for amplifier and switching applications.

MAXIMUM RATINGS (T _C =25°C)	SYMBOL	2N6053 2N6055	2N6054 2N6056	UNIT
Collector-Base Voltage Collector-Emitter Voltage Emitter-Base Voltage Collector Current Collector Current (Peak) Base Current Power Dissipation	VCBO VCEO VEBO IC ICM IB PD	60 60 5.0 8.0 16 120 100	80 80 5.0 8.0 16 120 100	V V A A mA W
Operating and Storage Junc. Temp.	T _j , T _{stg}	-65 TO +200		°C
Thermal Resistance	θJC	1.7	5	°C/W

ELECTRICAL CHARACTERISTICS (T_C=25°C)

SYMBOL	TEST CONDITIONS	MIN	MAX	UNIT
ICEV ICEV ICEO IEBO BVCEO VCE(SAT) VCE(SAT) VBE(SAT) VBE(ON) hFE hFE	$V_{CE}=Rated V_{CBO}, V_{EB}(OFF)=1.5V$ $V_{CE}=Rated V_{CBO}, V_{EB}(OFF)=1.5V, T_{C}=150^{\circ}C$ $V_{CE}=\frac{1}{2} Rated V_{CBO}$ $V_{BE}=5.0V$ $I_{C}=100mA (2N6053, 2N6055)$ $I_{C}=100mA (2N6054, 2N6056)$ $I_{C}=4.0A, I_{B}=16mA$ $I_{C}=8.0A, I_{B}=80mA$ $I_{C}=8.0A, I_{B}=80mA$ $V_{CE}=3.0V, I_{C}=4.0A$ $V_{CE}=3.0V, I_{C}=4.0A$ $V_{CE}=3.0V, I_{C}=8.0A$	60 80 750 100 300	0.5 5.0 0.5 2.0 2.0 3.0 4.0 2.8 18,000	mA mA W V V V V V V
^h fe fT C _{ob} C _{ob}	T $V_{CE}=3.0V, I_{C}=3.0A, f=1.0MHz$ VCB=10V, IE=0, f=0.1MHz (2N6053, 2N6054)	4.0	300 200	MHz pF pF

OUTSTANDING SUPPORT AND SUPERIOR SERVICES

PRODUCT SUPPORT

Central's operations team provides the highest level of support to insure product is delivered on-time.

- Supply management (Customer portals)
- Inventory bonding
- Consolidated shipping options

DESIGNER SUPPORT/SERVICES

Central's applications engineering team is ready to discuss your design challenges. Just ask.

- Free guick ship samples (2nd day air)
- Online technical data and parametric search
- SPICE models
- Custom electrical curves
- · Environmental regulation compliance
- Customer specific screening
- · Up-screening capabilities

· Custom product packing

Custom bar coding for shipments

- Special wafer diffusions
- PbSn plating options
- Package details
- Application notes
- · Application and design sample kits
- · Custom product and package development

REQUESTING PRODUCT PLATING

- If requesting Tin/Lead plated devices, add the suffix "TIN/LEAD" to the part number when 1. ordering (example: 2N2222A TIN/LEAD).
- 2. If requesting Lead (Pb) Free plated devices, add the suffix " PBFREE" to the part number when ordering (example: 2N2222A PBFREE).

CONTACT US

Corporate Headquarters & Customer Support Team

Central Semiconductor Corp. 145 Adams Avenue Hauppauge, NY 11788 USA Main Tel: (631) 435-1110 Main Fax: (631) 435-1824 Support Team Fax: (631) 435-3388 www.centralsemi.com

Worldwide Field Representatives: www.centralsemi.com/wwreps

Worldwide Distributors: www.centralsemi.com/wwdistributors

For the latest version of Central Semiconductor's LIMITATIONS AND DAMAGES DISCLAIMER. which is part of Central's Standard Terms and Conditions of sale, visit: www.centralsemi.com/terms



Mouser Electronics

Authorized Distributor

Click to View Pricing, Inventory, Delivery & Lifecycle Information:

Central Semiconductor: 2N6055 2N6053